Vishay Semiconductors

Small Signal Zener Diodes, Dual

Features

- Dual Silicon Planar Zener Diodes with Common Cathode or Common Anode configurations.
- Dual package provides for Bidirectional or separate unidirectional configurations.
- The dual configurations protect two separate lines with only one device.
- Peak Power: 40 W @1 ms (Bidirectional) .
- · Ideal for ESD Protection.
- For bidirectional operation, circuit connected to pins 1 and 2. For unidirectional operation, circuit connected to pins 1 and 3 or pins 2 and 3.

Mechanical Data

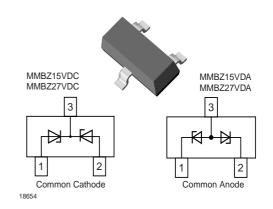
Case: SOT-23 Plastic case **Weight:** approx. 8.8 mg

Terminals: Solderable per MIL-STD-750, method

2026

Packaging Codes/Options:

GS18/ 10 k per 13 " reel (8 mm tape), 10 k/box GS08/ 3 k per 7 " reel (8 mm tape), 15 k/box



Marking:

 $\begin{array}{l} \text{MMBZ15VDC} = \text{TC5} \\ \text{MMBZ27VDC} = \text{TC7} \\ \text{MMBZ15VDA} = \text{TA5} \\ \text{MMBZ27VDA} = \text{TA7} \end{array}$

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

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Parameter	Test condition	Symbol	Value	Unit
Peak power dissipation ¹⁾		P _{PK}	40 ⁴⁾	W
Power dissipation	T _{amb} = 25 °C	P _{tot}	225	mW
on FR-5 Board ²⁾	Derate above 25 °C		1.8	mW/°C
Power dissipation	T _{amb} = 25 °C	P _{tot}	300	mW
on Alumina Substrate ³⁾	Derate above 25 °C		2.4	mW/°C

 $^{^{1)}}$ Nonrepetitive current pulse per Figure 2 and derate above T_{amb} = 25 °C per Figure 3.

Thermal Characteristics

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Thermal resistance junction to ambiant air		R_{thJA}	556	°C/W
Operating and storage temperature range		T _j , T _{stg}	- 55 to + 150	°C

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 $^{^{2)}}$ FR-5 = 1.0 x 0.75 x 0.62 in.

 $^{^{3)}}$ Alumina = 0.4 x 0.3 x 0.024 in., 99.5 % alumina.

⁴⁾ The MMBZ6V8DC/A is rated at 24 V.

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Electrical Characteristics

Partnumber	Break	down	Test	Working	Max.	Max.	Max. Reverse	Max.	Max. Forward	
	Voltage ¹⁾		Current	Peak	Reverse	Reverse	Voltage	Temperature	Volt	age
		ŭ		Reverse	Leakage	Surge	(Clamping	Coefficient		
				Voltage	Current	Current	Voltage)			
	V_{BR}	at I _T	I _T	V_{RWM}	I _R	I _{PP}	V _C @ I _{RSM} ²⁾	at V _{BR}	V _F	@ I _F
	\	/	mA	V	nA	А	V	mV/°C	V	mA
	min	max								
MMBZ15VDA	14.70	15.30	1.0	12.8	100	1.9	21.2	16	0.9	200
MMBZ27VDA	26.46	27.54	1.0	22.0	80	1.0	38.0	30	1.1	200
MMBZ15VDC	14.30	15.80	1.0	12.8	100	1.9	21.2	16	0.9	200
MMBZ27VDC	25.65	28.35	1.0	22.0	80	1.0	38.0	30	1.1	200

Note

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)

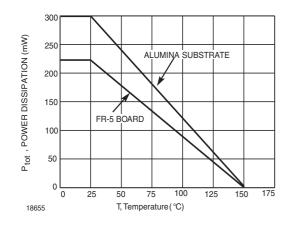


Figure 1. Steady State Power Derating Curve

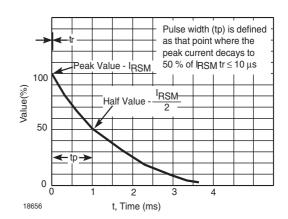


Figure 2. Pulse Waveform

 $^{^{1)}\,}V_{BR}$ measured at pulse test current I_{T} at an ambient temperature of 25 $^{\circ}C$

²⁾ Surge current waveform per Figure 2 and derate per Figure 3

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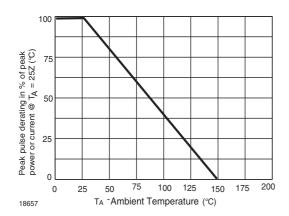
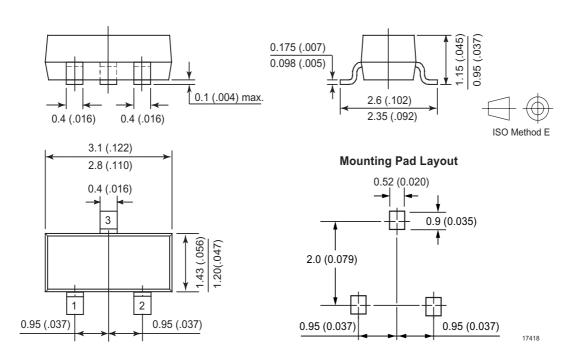


Figure 3. Pulse Derating Curve

Package Dimensions in mm (Inches)



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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operatingsystems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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